NSN 5961-01-461-4289

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Inclosure Material:
Plastic
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.00 reverse voltage, dc and 400.00 repetitive peak reverse voltage and 400.00 working peak reverse voltage
Current Rating Per Characteristic:
800.00 amperes peak forward surge current nanoamperes and 0.80 amperes collector current, dc and 60.00 amperes forward current,
average blank and 60.00 amperes collector current, dc not applicable
Terminal Type And Quantity:
2 solder stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0